

PNP -1.0A -50V Middle Power Transistor

Parameter	Value
$V_{\sf CEO}$	-50V
I _C	-1.0A

Features

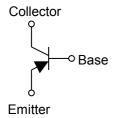
- 1) Suitable for Middle Power Driver
- 2) Complementary NPN Types: 2SCR513P
- 3) Low V_{CE(sat)}

$$V_{CE(sat)} = -0.4V(Max.)$$

 $(I_C/I_B = -500mA/ -25mA)$

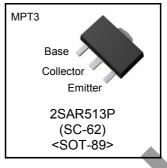
4) Lead Free/RoHS Compliant.

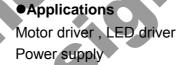
•Inner circuit



●Packaging specifications







Part No.	Package	Package size (mm)	Taping code	Reel size (mm)	Tape width (mm)	Basic ordering unit (pcs)	Marking
2SAR513P	MPT3	4540	T100	180	12	1,000	MC

● Absolute maximum ratings (Ta = 25°C)

Parameter		Symbol	Values	Unit
Collector-base voltage		V_{CBO}	-50	V
Collector-emitter voltage		V_{CEO}	-50	V
Emitter-base voltage		V_{EBO}	-6	V
Collector current	DC	I _C	-1.0	А
	Pulsed	I _{CP} *1	-2.0	А
Power dissipation		P_{D}^{*2}	0.5	W
		P _D *3	2.0	W
Junction temperature		T _j	150	°C
Range of storage temperature		T _{stg}	−55 to +150	°C

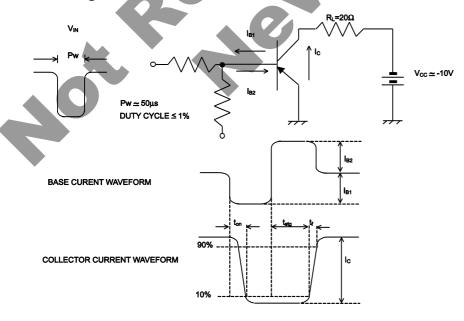
- *1 Pw=10ms, single pulse
- *2 Each terminal mounted on a reference land
- *3 Mounted on a ceramic board (40×40×0.7mm)

●Electrical characteristics(Ta = 25°C)

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Collector-emitter breakdown voltage	BV _{CEO}	I _C = -1mA	-50	-	-	V
Collector-base breakdown voltage	BV _{CBO}	$I_{C} = -100 \mu A$	-50	-	-	V
Emitter-base breakdown voltage	BV _{EBO}	$I_E = -100 \mu A$	- 6	ı	-	V
Collector cut-off current	I _{CBO}	V _{CB} = -50V	ı	-	7	μΑ
Emitter cut-off current	I _{EBO}	V _{EB} = -4V	-	<u>_</u>	-1	μА
Collector-emitter saturation voltage	V _{CE(sat)} *1	$I_C = -500 \text{mA}, I_B = -25 \text{mA}$		-0.20	-0.40	V
DC current gain	h _{FE}	$V_{CE} = -2V, I_{C} = -50 \text{mA}$	180	-	450	-
Transition frequency	f _⊤	$V_{CE} = -10V, I_{E} = -200 \text{mA}$ f=100MH _Z	-	400	-	MHz
Output capacitance	C _{ob}	$V_{CB} = -10V, I_{E} = 0A$ f = 1MHz	-	12	-	pF
Turn-on time	t _{on} *2	I _C = -0.5A		40	-	ns
Storage time	t _{stg} *2	I _{B1} = -50mA I _{B2} =50mA	-	250	-	ns
Fall time	t _f *2	V _{CC} [≃] −10V	-	35	-	ns

^{*1} Pulsed

•Switching time test circuit



^{*2} See switching time test circuit

●Electrical characteristic curves(Ta = 25°C)

Fig.1 Ground Emitter Propagation Characteristics

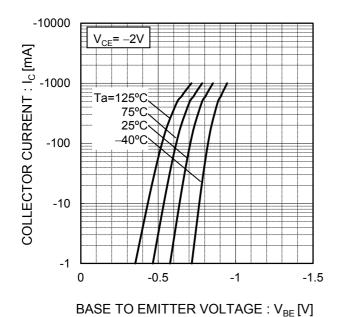
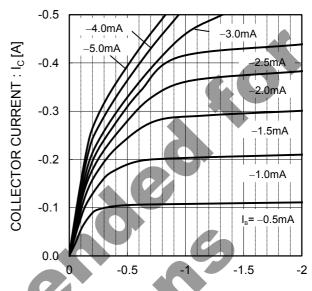


Fig.2 Typical Output Characteristics



COLECTOR TO EMITTE VOLTAGE : V_{CE}[V]

Fig.3 DC Current Gain vs. Collector Current(I)

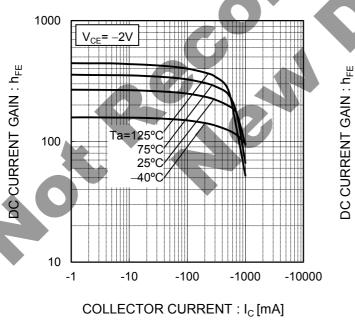
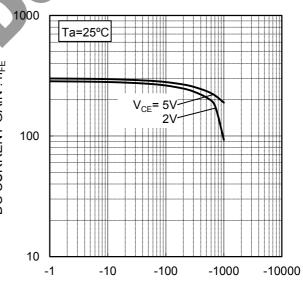


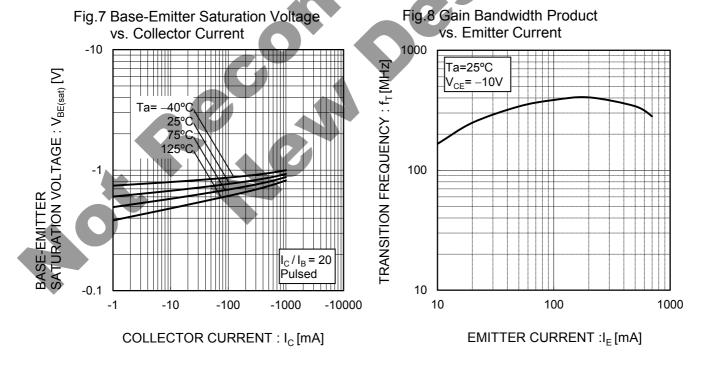
Fig.4 DC current gain vs. output current (II)



COLLECTOR CURRENT : I_C [mA]

●Electrical characteristic curves(Ta = 25°C)

Fig.6 Collector-Emitter Saturation Voltage Fig.5 Collector-Emitter Saturation Voltage vs. Collector Current (II) vs. Collector Current (I) -1 $I_C/I_B = 20$ Ta=25°C COLLECTOR-EMITTER SATURATION VOLTAGE : V_{CE(sat)} [V] SATURATION VOLTAGE: V_{CE(sat)} [V] -0.1 -0.1 COLLECTOR-EMITTER Ta=125°C 75°C 20 25°C -0.01 -0.01 40°C -0.001 -0.001 -1 -10 -100 -1000 -10000 -100 -1000 -10000 COLLECTOR CURRENT : I_C [mA] COLLECTOR CURRENT : I_C [mA]



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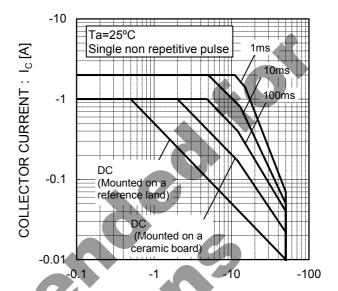
●Electrical characteristic curves(Ta = 25°C)

Fig.9 Emitter input capacitance vs.
Emitter-Base Voltage
Collector output capacitance vs.
Collector-Base Voltage

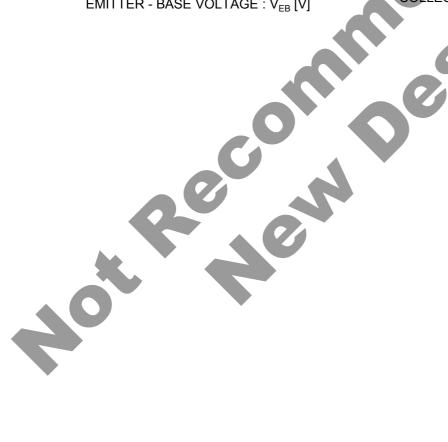
1000
Ta=25°C
f=1MHz
I_E=0A
I_C=0A

COLLECTOR - BASE VOLTAGE : V_{CB} [V] EMITTER - BASE VOLTAGE : V_{EB} [V]

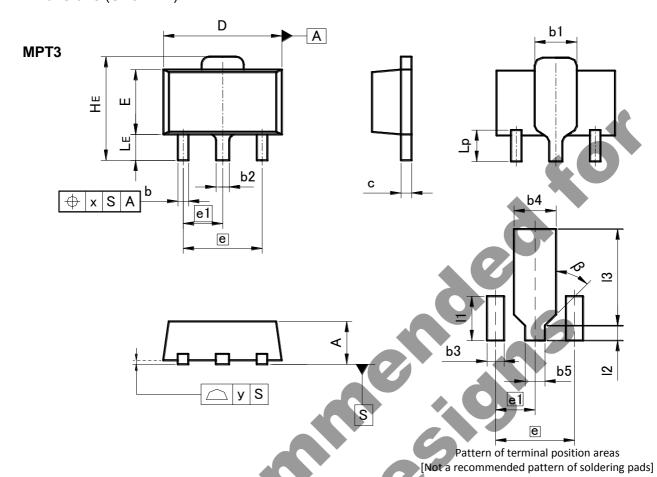
Fig. 10 Safe Operating Area



COLLECTOR TO EMITTER VOLTAGE : V_{CE} [V]



●Dimensions (Unit: mm)



DIM	MILIM	ETERS	INCHES		
DIW	MIN	MAX	MIN	MAX	
Α	1.40	1.50	0.055	0.059	
b	0.30	0.50	0.012	0.020	
b1	1.50	1.70	0.059	0.067	
b2	0.40	0.60	0.016	0.024	
C	0.35	0.50	0.014	0.020	
D	4.40	4.70	0.173	0.185	
E	2.40	2.70	0.094	0.106	
е	3.0	00	0.1	18	
e1	1.	50	0.0	59	
HE	3.70	4.30	0.146	0.169	
LE	0.80	1.20	0.031	0.047	
Lp	1.01	1.41	0.040	0.056	
X	_	0.15	_	0.006	
У	_	0.10	_	0.004	

DIM	MILIMETERS		INCHES		
	MIN	MAX	MIN	MAX	
b3	_	0.65	-	0.026	
b4	_	1.70	-	0.067	
b5	_	0.75	-	0.030	
11	_	1.71	1	0.067	
12	_	0.58	1	0.023	
13	_	3.72	_	0.146	
β	45°		45°		

Dimension in mm / inches

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